NSN 5961-01-443-6294

Diode Semiconductor Device - Page 1 of 1



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Mounting Facility Quantity:
1
Mounting Method:
Threaded stud
Thready Qty Per Inch (tpi):
32
Thread Size:
0.138 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 regulator voltage, dc
Current Rating Per Characteristic:
10.00 microamperes forward current, average peak
Power Rating Per Characteristic:
10.0 watts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius case
Thread Series Designator:
Unc
Terminal Type And Quantity:
2 ribbon
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A110a0